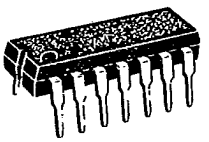
MN4068B/MN4068BS

8-Input NAND Gates

■ Description

The MN4068B/S are positive 8-input NAND gates.
The outputs are fully buffered to improve the propagation characteristics between the input and output which are affected by increasing load capacitance and minimizes propagation delay time.

P-1

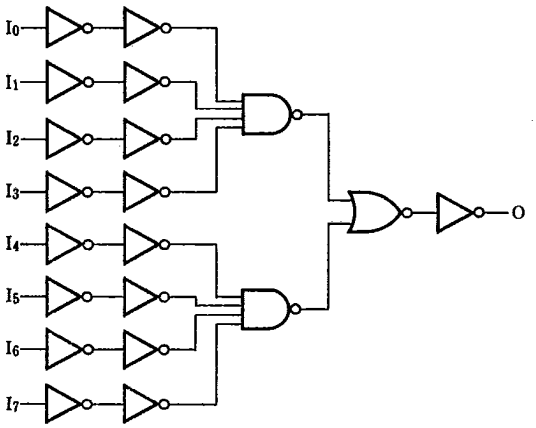


14-Pin • Plastic DIL Package

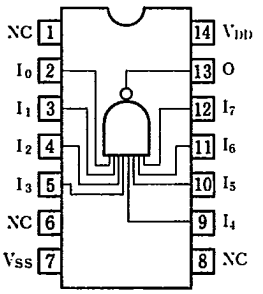
P-2

14-Pin • Panaflat Package (SO-14D)

■ Logic Diagram



Pin Configuration



■ Maximum Ratings (Ta=25℃)

Item		Symbol	Ratings	Unit
Supply Voltage		V_{DD}	−0.5~+18	V
Input Voltage		V_I	−0.5~V_{DD}+0.5*	V
Output Voltage		V_O	−0.5~V_{DD}+0.5*	V
Peak Input · Output Current		$\pm I_I$	max. 10	mA
Power Dissipation (per package)	Ta=−40~+60℃	P_D	max. 400	mW
	Ta=+60~+85℃		Decrease up to 200mW rating at 8mW/°C	
Power Dissipation (per output terminal)		P_D	max. 100	mW
Operating Ambient Temperature		Topr	−40~+85	℃
Storage Temperature		Tstg	−65~+150	℃

* V_{DD} + 0.5V should be under 18V

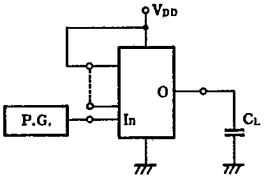
DC Characteristics (V_{SS}=0V)

Item	V_{DD} (V)	Symbol	Conditions		Ta=−40℃ min.	Ta=−40℃ max.	Ta=25℃ min.	Ta=25℃ max.	Ta=85℃ min.	Ta=85℃ max.	Unit
Quiescent Power Supply Current	5	I_{DD}	V_I=V_{SS} or V_{DD}		—	1	—	1	—	7.5	μA
	10				—	2	—	2	—	15	
	15				—	4	—	4	—	30	
Output Voltage Low Level	5	V_{OL}	V_I=V_{SS} or V_{DD}		—	0.05	—	0.05	—	0.05	V
	10		$\|I_O\|$<1μA		—	0.05	—	0.05	—	0.05	
	15				—	0.05	—	0.05	—	0.05	
Output Voltage High Level	5	V_{OH}	V_I=V_{SS} or V_{DD}		4.95	—	4.95	—	4.95	—	V
	10		$\|I_O\|$<1μA		9.95	—	9.95	—	9.95	—	
	15				14.95	—	14.95	—	14.95	—	
Input Voltage Low Level	5	V_{IL}	$\|I_O\|$<1μA	V_O=0.5V or 4.5V	—	1.5	—	1.5	—	1.5	V
	10			V_O=1V or 9V	—	3	—	3	—	3	
	15			V_O=1.5V or 13.5V	—	4	—	4	—	4	
Input Voltage High Level	5	V_{IH}	$\|I_O\|$<1μA	V_O=0.5V or 4.5V	3.5	—	3.5	—	3.5	—	V
	10			V_O=1V or 9V	7	—	7	—	7	—	
	15			V_O=1.5V or 13.5V	11	—	11	—	11	—	
Output Current Low Level	5	I_{OL}	V_O=0.4V, V_I=0 or 5V		0.52	—	0.44	—	0.36	—	mA
	10		V_O=0.5V, V_I=0 or 10V		1.3	—	1.1	—	0.9	—	
	15		V_O=1.5V, V_I=0 or 15V		3.6	—	3	—	2.4	—	
Output Current High Level	5	$-I_{OH}$	V_O=4.6V, V_I=0 or 5V		0.52	—	0.44	—	0.36	—	mA
	10		V_O=9.5V, V_I=0 or 10V		1.3	—	1.1	—	0.9	—	
	15		V_O=13.5V, V_I=0 or 15V		3.6	—	3	—	2.4	—	
Output Current High Level	5	$-I_{OH}$	V_O=2.5V, V_I=0 or 5V		1.7	—	1.4	—	1.1	—	mA
Input Leakage Current	15	$\pm I_I$	V_I=0 or 15V		—	0.3	—	0.3	—	1	μA

Switching Characteristics (Ta=25℃, V_{SS}=0V, C_L=50pF)

Item	V_{DD} (V)	Symbol	min.	typ.	max.	Unit
Output Rise Time	5	t_{TLH}	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Output Fall Time	5	t_{THL}	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Propagation Delay Time I−O (H→L)	5	t_{PHL}	—	95	285	ns
	10		—	40	120	
	15		—	30	90	
Propagation Delay Time I−O (L→H)	5	t_{PLH}	—	80	240	ns
	10		—	35	105	
	15		—	30	90	
Input Capacitance		C_I	—	—	7.5	pF

1. Switching Time Test Circuit



2. Waveforms